BAS70/ -04/ -05/ -06

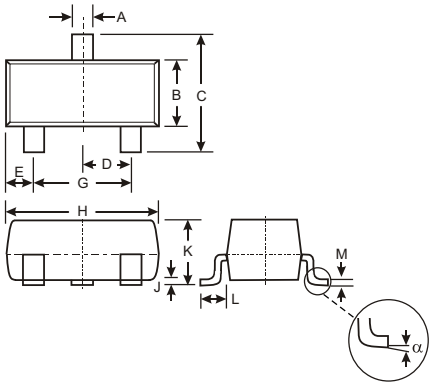
SURFACE MOUNT SCHOTTKY BARRIER DIODE

Features

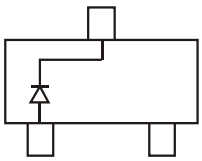
- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection
- **Lead Free/RoHS Compliant (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

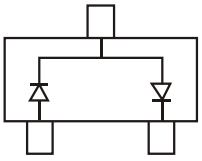
- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020C
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe)
- Polarity: See Diagrams Below
- Marking: See Diagrams Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)



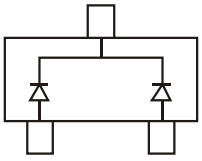
SOT-23		
Dim	**Min**	**Max**
A	0.37	0.51
B	1.20	1.40
C	2.30	2.50
D	0.89	1.03
E	0.45	0.60
G	1.78	2.05
H	2.80	3.00
J	0.013	0.10
K	0.903	1.10
L	0.45	0.61
M	0.085	0.180
	0	8
All Dimensions in mm		



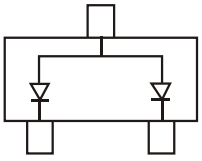
BAS70 Marking: K73, K7C



BAS70-04 Marking: K74, K7D



BAS70-05 Marking: K75, K7E



BAS70-06 Marking: K76, K7F

Maximum Ratings and Electrical Characteristics, Single Diode @ T_A = 25 C unless otherwise specified

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	70	V
RMS Reverse Voltage	$V_{R(RMS)}$	49	V
Maximum Forward Continuous Current (Note 1)	I_{FM}	70	mA
Non-Repetitive Peak Forward Surge Current @ t 1.0s	I_{FSM}	100	mA
Power Dissipation (Note 1)	P_d	200	mW
Thermal Resistance Junction to Ambient Air (Note 1)	R_{JA}	625	°C/W
Operating Junction Temperature Range	T_j	-55 to +125	C
Storage Temperature Range	T_{STG}	-65 to +150	°C

Electrical Ratings @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	$V_{(BR)R}$	70	—	V	I_R = 10
Forward Voltage	V_F	—	410 1000	mV	t_p <300µs, I_F = 1.0mA t_p <300µs, I_F = 15mA
Reverse Current (Note 2)	I_R		100	nA	t_p < 300µs, V_R = 50V
Total Capacitance	C_T		2.0	pF	V_R = 0V, f = 1.0MHz
Reverse Recovery Time	t_{rr}	—	5.0	ns	I_F = I_R = 10mA to I_R = 1.0mA, R_L =100

Notes:
1. Part mounted on FR-4 board with recommended pad layout, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
2. Short duration pulse test used to minimize self-heating effect.
3. No purposefully added lead.

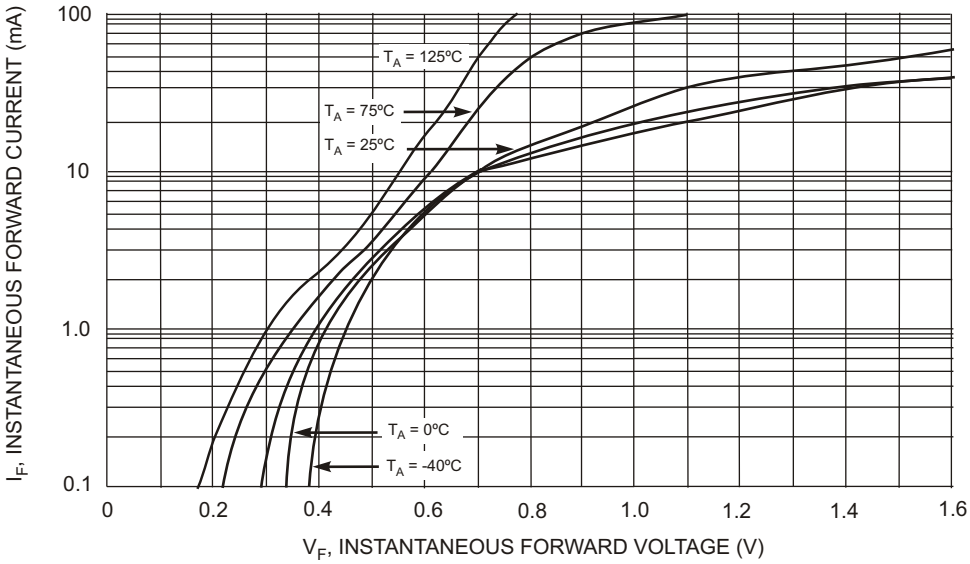


Fig. 1 Typical Forward Characteristics

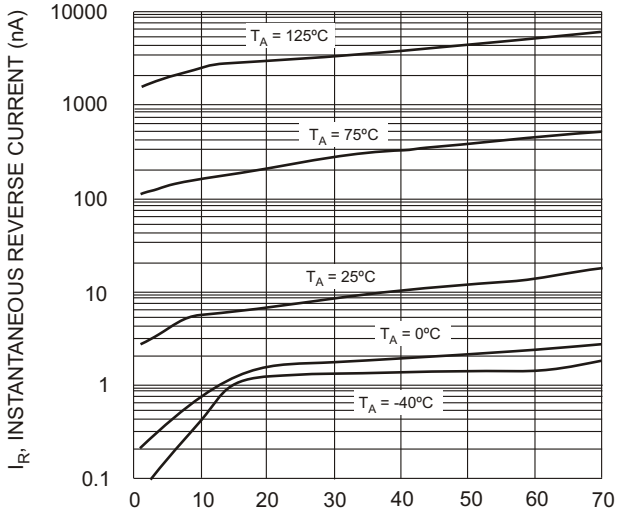


Fig. 2 Typical Reverse Characteristics

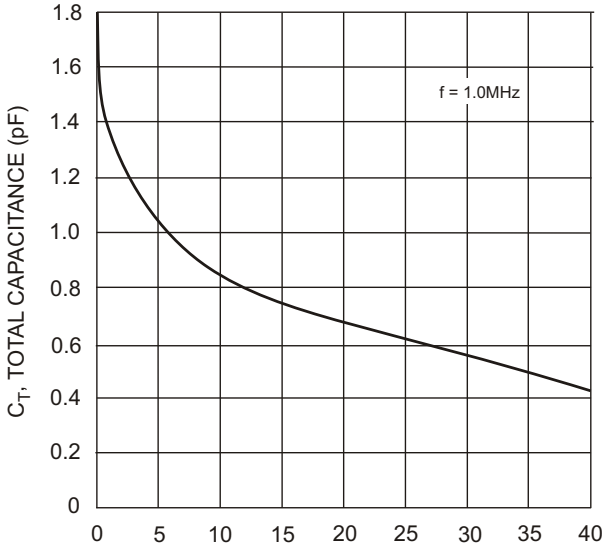


Fig. 3 Typical Total Capacitance vs. Reverse Voltage

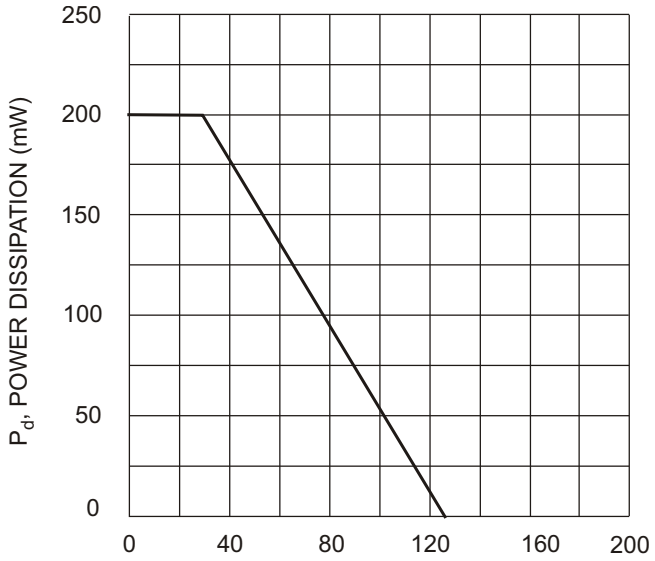


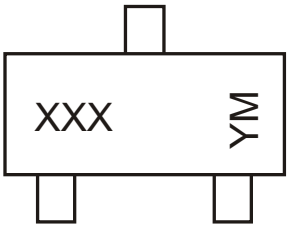
Fig. 4 Power Derating Curve, Total Package

Ordering Information (Note 4)

Device	Packaging	Shipping
BAS70-7-F	SOT-23	3000/Tape & Reel
BAS70-04-7-F	SOT-23	3000/Tape & Reel
BAS70-05--7-F	SOT-23	3000/Tape & Reel
BAS70-06-7-F	SOT-23	3000/Tape & Reel

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code (See Page 1)
YM = Date Code Marking
Y = Year ex: T = 2006
M = Month ex: 9 = September

Date Code Key

Year	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	M	N	P	R	S	T	U	V	W	X	Y	Z

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D